



ON Semiconductor®

<http://onsemi.com>

6HP04CH

P-Channel Small Single MOSFET –60V, –370mA, 4.2Ω, Single CPH3

Features

- 4V drive
- Halogen free compliance
- Protection diode in

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	V _{DSS}		–60	V
Gate to Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		–370	mA
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	–1480	mA
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (900mm ² ×0.8mm)	0.6	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		–55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Electrical Characteristics at Ta=25°C

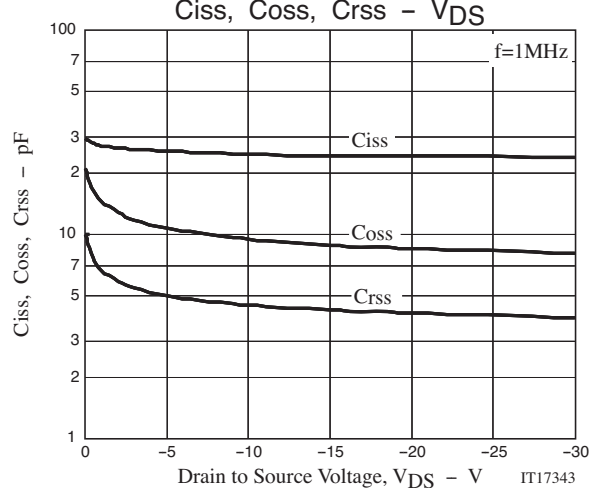
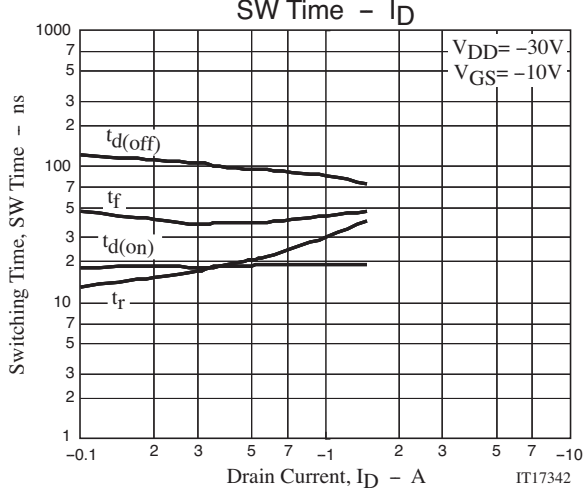
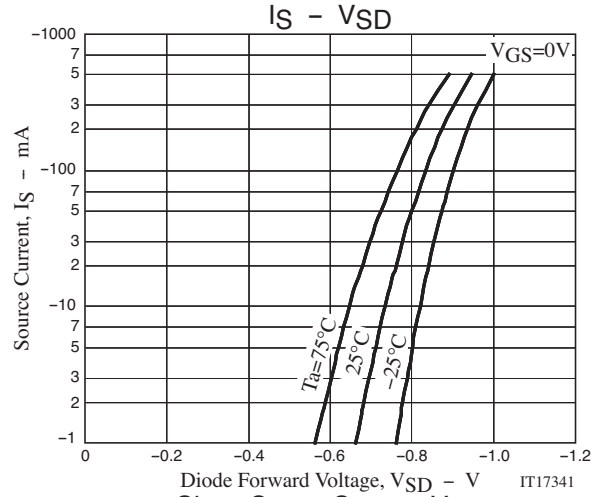
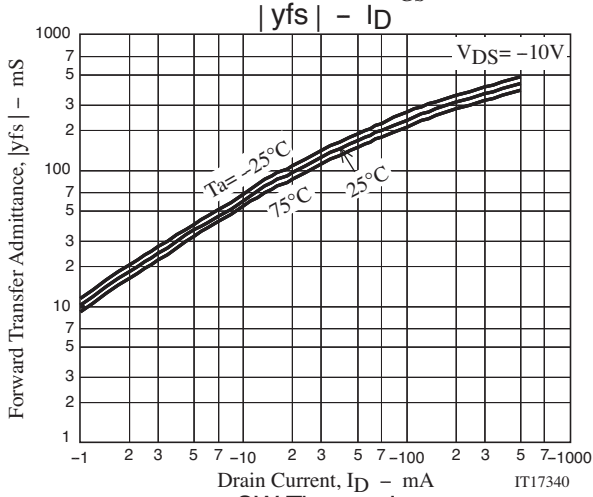
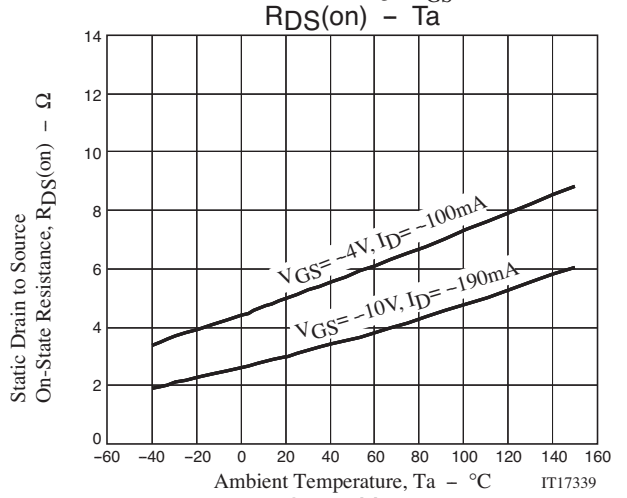
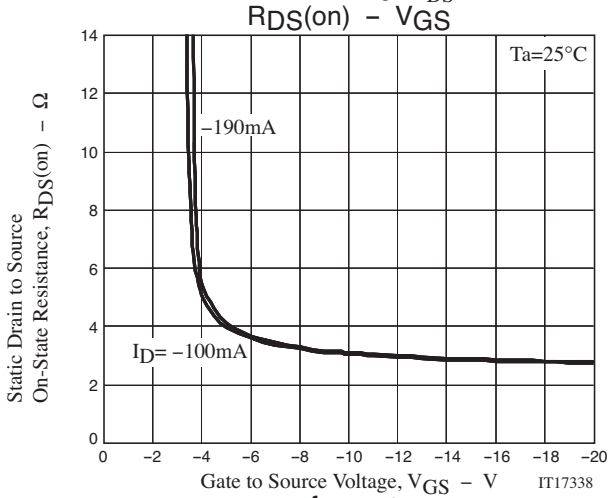
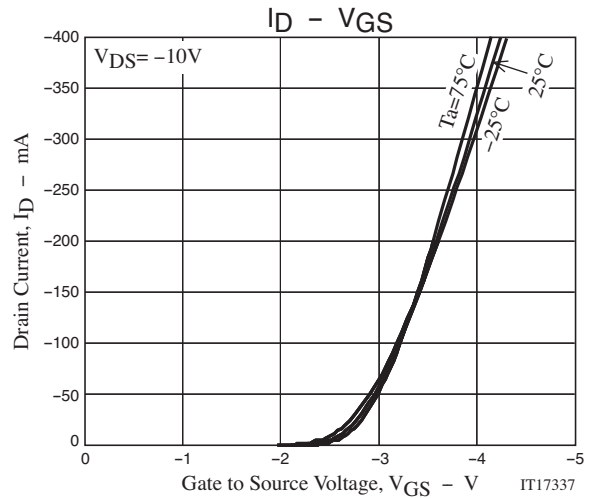
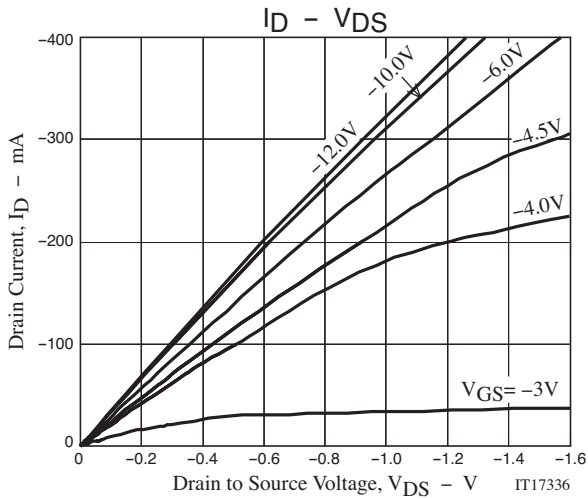
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	V _{(BR)DSS}	I _D =–1mA, V _{GS} =0V	–60			V
Zero-Gate Voltage Drain Current	I _{DSS}	V _{DS} =–60V, V _{GS} =0V			–1	μA
Gate to Source Leakage Current	I _{GSS}	V _{GS} =±16V, V _{DS} =0V			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =–10V, I _D =–100μA	–1.2		–2.6	V
Forward Transfer Admittance	y _{fs}	V _{DS} =–10V, I _D =–190mA		310		mS
Static Drain to Source On-State Resistance	R _{DS(on)1}	I _D =–190mA, V _{GS} =–10V		3.1	4.2	Ω
	R _{DS(on)2}	I _D =–100mA, V _{GS} =–4V		5.1	7.3	Ω
Input Capacitance	C _{iss}	V _{DS} =–20V, f=1MHz		24.1		pF
Output Capacitance	C _{oss}			8.5		pF
Reverse Transfer Capacitance	C _{rss}			4.1		pF
Turn-ON Delay Time	t _{d(on)}			18.4		ns
Rise Time	t _r	See specified Test Circuit.		15.2		ns
Turn-OFF Delay Time	t _{d(off)}			113		ns
Fall Time	t _f			41		ns
Total Gate Charge	Q _g	V _{DS} =–30V, V _{GS} =–10V, I _D =–370mA		0.84		nC
Gate to Source Charge	Q _{gs}			0.19		nC
Gate to Drain "Miller" Charge	Q _{gd}			0.21		nC
Diode Forward Voltage	V _{SD}	I _S =–370mA, V _{GS} =0V		–0.92	–1.2	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

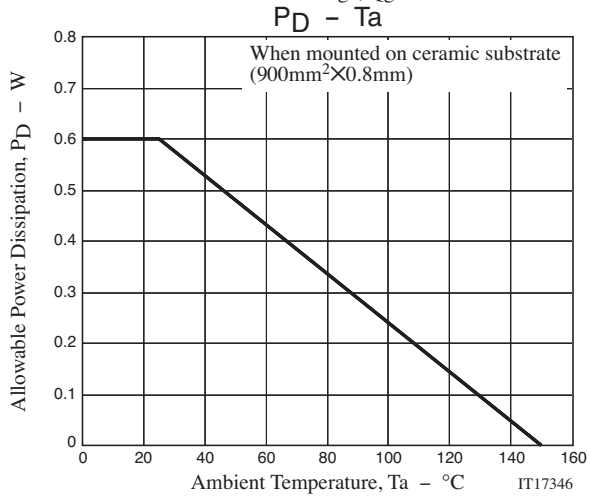
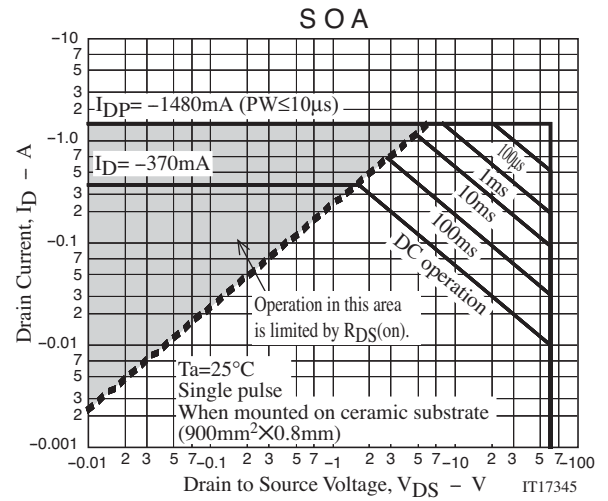
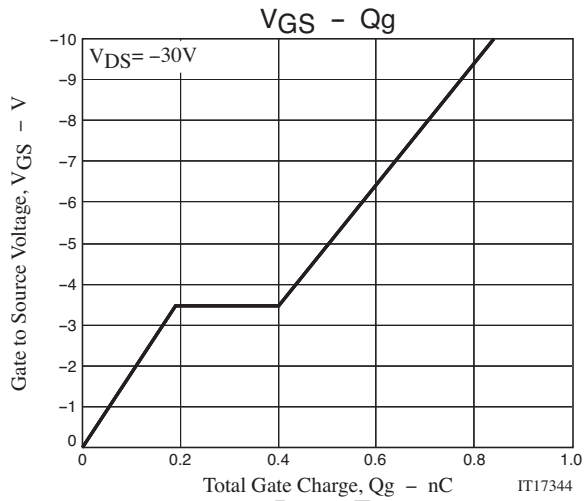
ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

6HP04CH



6HP04CH



6HP04CH

Package Dimensions

6HP04CH-TL-W

CPH3

CASE 318BA

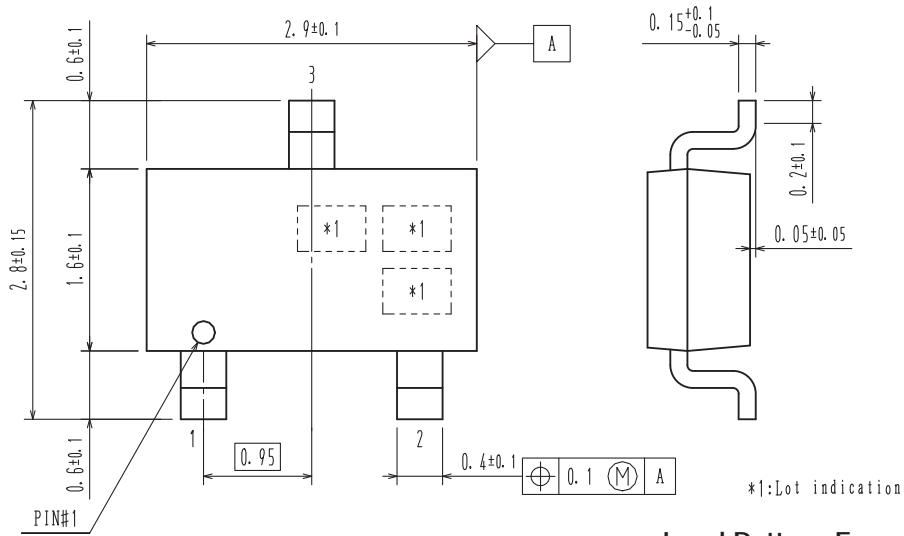
ISSUE O

Unit : mm

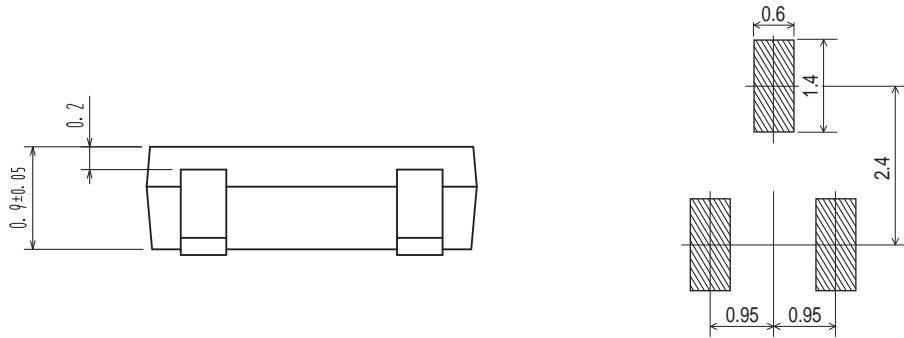
1: Gate

2: Source

3: Drain



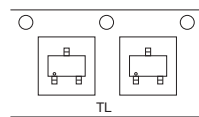
Land Pattern Example



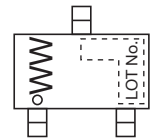
Ordering & Package Information

Device	Package	Shipping	memo
6HP04CH-TL-W	CPH3, SC-59 SOT-23, TO-236	3,000 pcs. / reel	Pb-Free and Halogen Free

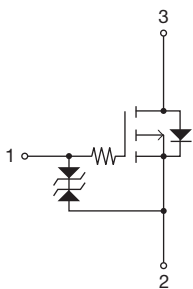
Packing Type:TL



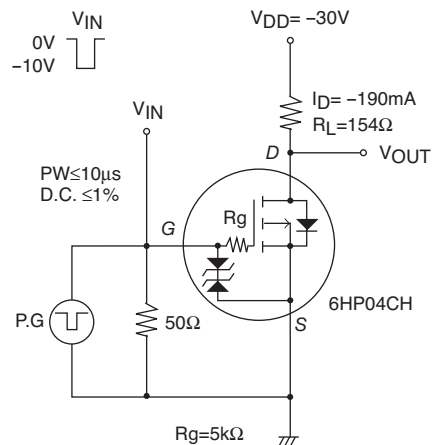
Marking



Electrical Connection



Switching Time Test Circuit



Note on usage : Since the 6HP04CH is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.